# Clock OSC

# SG5032CCN

Product name SG5032CCN 5.500000 MHz HJGA
Product Number / Ordering code X1G0044710014xx

Please refer to the 8.Packing information about xx (last 2 digits)

Output waveform CMOS

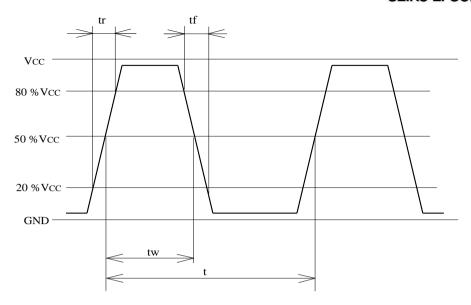
Pb free / Complies with EU RoHS directive

Reference weight Typ. 52 mg

| 1.Absolute maximum ratings |         |      |      |         |      |                           |  |
|----------------------------|---------|------|------|---------|------|---------------------------|--|
| Parameter                  | Symbol  | Min. | Тур. | Max.    | Unit | Conditions / Remarks      |  |
| Maximum supply voltage     | Vcc-GND | -0.3 | -    | +7      | V    | -                         |  |
| Storage temperature        | T_stg   | -40  | -    | +125    | ٥C   | Storage as single product |  |
| Input voltage              | Vin     | -0.5 | -    | Vcc+0.5 | V    | OE terminal               |  |

| 2.Specifications(charact | eristics)        |         |          |        |                   |   |
|--------------------------|------------------|---------|----------|--------|-------------------|---|
| Parameter                | Symbol           | Min.    | Тур.     | Max.   | Unit              | Conditions / Remarks                      |
| Output frequency         | f0               |         | 5.500000 |        | MHz               |   |
| Supply voltage           | Vcc              | 4.5     | 5        | 5.5    | V                 | -   |
| Operating temperature    | T_use            | -40     | -        | +85    | ٥C                | -   |
| Frequency tolerance      | f_tol            | -50     | •        | 50     | x10 <sup>-6</sup> | T_use                                     |
| Current consumption      | Icc              | -       | -        | 20     | mA                | No load condition                         |
| Stand-by current         | I_std            | -       | ı        | -      | μΑ                | -   |
| Disable current          | I_dis            | -       | -        | 10.0   | mA                | OE = GND                                  |
| Symmetry                 | SYM              | 40      | -        | 60     | %                 | 50% Vcc Level L_CMOS=<50pF                |
| Output voltage           | V <sub>OH</sub>  | Vcc-0.4 | -        | -      |                   | -   |
|                          | V <sub>OL</sub>  | -       | 1        | 0.4    |                   | -   |
| Output load condition    | L_CMOS           | -       | -        | 50     | pF                | CMOS Load                                 |
| Input voltage            | $V_{IH}$         | 0.8Vcc  | 1        | -      |                   | OE terminal                               |
|                          | $V_{IL}$         | -       | -        | 0.2Vcc |                   | OE terminal                               |
| Rise time                | t <sub>r</sub>   | -       | -        | 5      | ns                | 0.2Vcc to 0.8Vcc Level, L_CMOS=50pF       |
| Fall time                | tf               | -       | -        | 5      | ns                | 0.2Vcc to 0.8Vcc Level, L_CMOS=50pF       |
| Start-up time            | t_str            | -       | -        | 5      | ms                | t = 0 at 0.9Vcc                           |
| Jitter                   | t <sub>DJ</sub>  | -       | TBD      | -      | ps                | Deterministic Jitter                      |
|                          | t <sub>RJ</sub>  | -       | TBD      | -      | ps                | Random Jitter                             |
|                          | t <sub>RMS</sub> | -       | TBD      | -      | ps                | δ(RMS of total distribution)              |
|                          | t <sub>p-p</sub> | -       | TBD      | -      | ps                | Peak to Peak                              |
|                          | t <sub>acc</sub> | -       | -        | -      | ps                | Accumulated Jitter(δ) n=2 to 50000 cycles |
| Phase jitter             | t <sub>PJ</sub>  | -       | TBD      | -      | ps                | Off set Frequency: 12kHz to 20MHz         |
| Phase noise              | L(f)             | -       | -        | -      | dBc/Hz            | Off set 1Hz                               |
|                          |                  | -       | TBD      | -      | dBc/Hz            | Off set 10Hz                              |
|                          |                  | -       | TBD      | -      | dBc/Hz            | Off set 100Hz Vcc=3.3V                    |
|                          |                  | -       | TBD      | -      | dBc/Hz            | Off set 1kHz                              |
|                          |                  | -       | TBD      | -      | dBc/Hz            | Off set 10kHz                             |
|                          |                  | -       | TBD      | -      | dBc/Hz            | Off set 100kHz Vcc=3.3V                   |
|                          |                  | -       | TBD      | -      | dBc/Hz            | Off set 1MHz                              |
| Frequency aging          | f_age            | -5      | -        | 5      | x10 <sup>-6</sup> | @+25°C first year                         |
|                          |                  | -       |          | -      |                   | -   |

# 3.Timing chart



## 4.Test circuit

touit

1) Waveform observation

VCC

ST

OF

OE

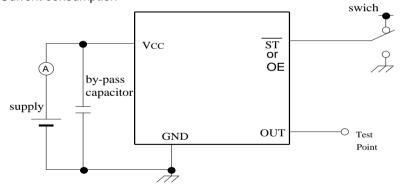
Supply

GND

OUT

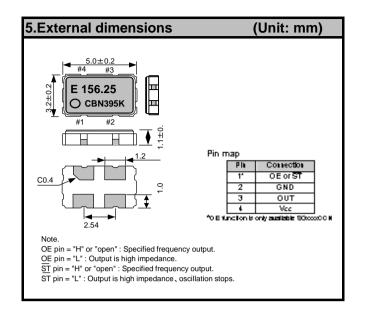
L\_CMOS

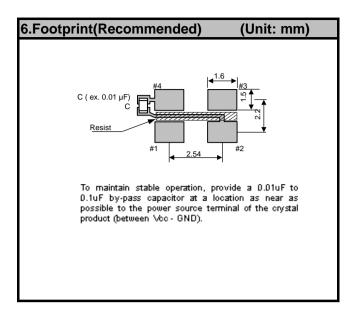
2) Current consumption

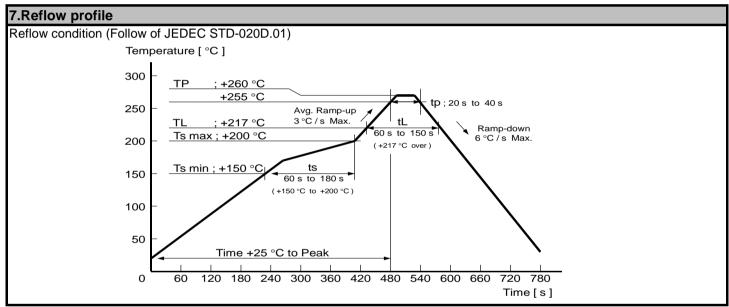


\*Current consumption under the disable function should be = GND.

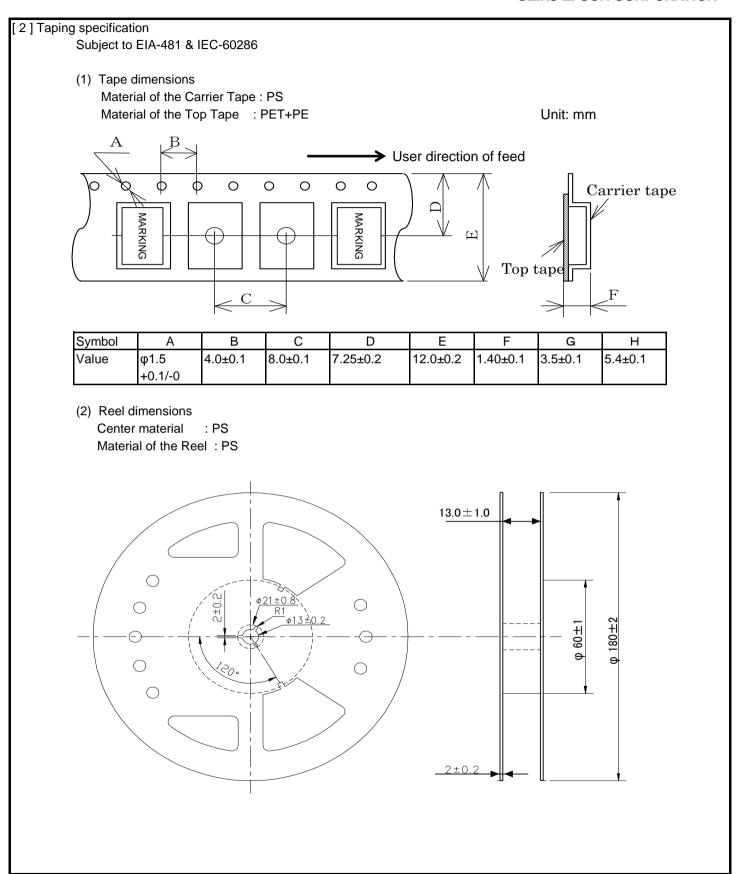
- 3) Condition
- (1) Oscilloscope
- · Band width should be minimum 5 times higher (wider) than measurement frequency.
- · Probe earth should be placed closely from test point and lead length should be as short as possible
- \* Recommendable to use miniature socket. (Don't use earth lead.)
- (2) L\_CMOS also includes probe capacitance.
- (3) By-pass capacitor (0.01  $\mu$ F to 0.1  $\mu$ F) is placed closely between VCC and GND.
- (4) Use the current meter whose internal impedance value is small.
- (5) Power supply
- Start up time (0 %VCC to 90 %VCC) of power source should be more than 150 µs.
- · Impedance of power supply should be as lowest as possible.







| 8.Packing | g informa  | tion                         |                              |                |  |
|-----------|--|------------------------------|------------------------------|----------------|--|
| [1]Produc | 1 ]Product number last 2 digits code(xx) description |                              | The recommended code is "00" |                |  |
|           | X1G0044  | 710014xx                     |                              |                |  |
|           | Code   | Condition                    | Code                         | Condition      |  |
|           | 01   | Any Q'ty vinyl bag(Tape cut) | 13                           | 500pcs / Reel  |  |
|           | 11   | Any Q'ty / Reel              | 00                           | 1000pcs / Reel |  |
|           | 12   | 250pcs / Reel                |                              |                |  |



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